



DONGGUAN NANJING ELECTRONICS LTD.,
Plastic-Encapsulate MOSFETS

NJ7N70 N - Channel Power MOSFET

MAIN CHARACTERISTICS

I_D	7A
V_{DSS}	700V
$R_{DS(on)-typ}$ (@ $V_{GS}=10V$)	1.45 Ω

FEATURES

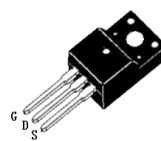
- Fast Switching
- Low ON Resistance
- Low Gate Charge
- 100% Single Pulse avalanche energy Test

APPLICATIONS

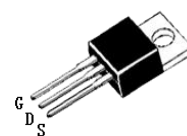
- Power switch circuit of adaptor and charger.

MECHANICAL DATA

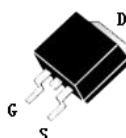
- Case: Molded plastic
- Mounting Position: Any
- Molded Plastic: UL Flammability Classification Rating 94V-0
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Solder bath temperature 275°C maximum, 10s per JESD 22-B106



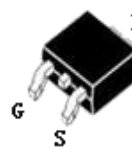
TO-220F



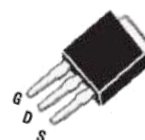
TO-220AB



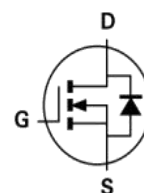
TO-263



TO-252



TO-251



Product specification classification

Part Number	Package	Mode Name	Pack
NJ7N70	TO-220AB	NJ7N70	Tube
NJ7N70F	TO-220F (0.5mm)	NJ7N70F	Tube
NJ7N70B	TO-263	NJ7N70B	Tube
NJ7N70B	TO-263	NJ7N70B	Tape
NJ7N70A	TO-251	NJ7N70A	Tube
NJ7N70D	TO-252	NJ7N70D	Tape

MOSFET ELECTRICAL CHARACTERISTICS

Characteristics	Symbol	Value			Unit
		220AB/263	220F	251/252	
Drain-Source Voltage	V_{DS}	700			V
Gate-Source Voltage	V_{GS}	± 30			V
Continue Drain Current	I_D	7			A
Pulsed Drain Current (Note1)	I_{DM}	28			A
Power Dissipation	P_D	100	35	100	W
Single Pulse Avalanche Energy (Note1)	E_{AS}	350			mJ
Operating Temperature Range	T_J	150			$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-55 to +150			$^{\circ}\text{C}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.25	3.57	1.25	$^{\circ}\text{C/W}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	62.5	62.5	100	$^{\circ}\text{C/W}$

Note1:Pulse test: 300 μs pulse width, 2 % duty cycle

Electrical Characteristics at $T_c=25^{\circ}\text{C}$ unless otherwise specified

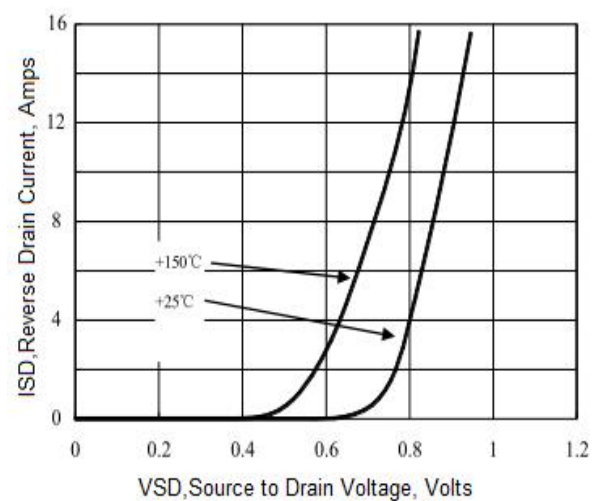
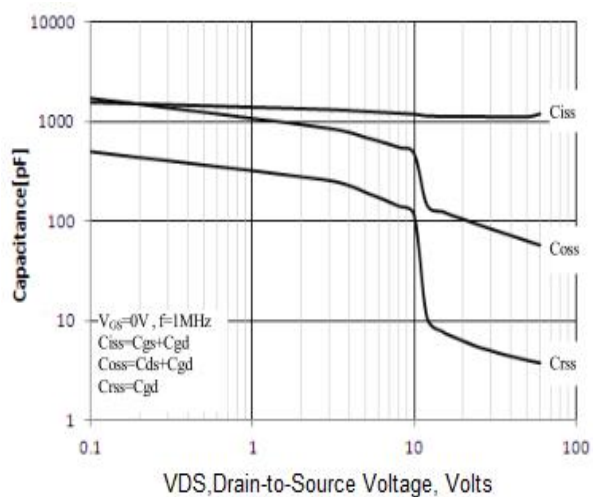
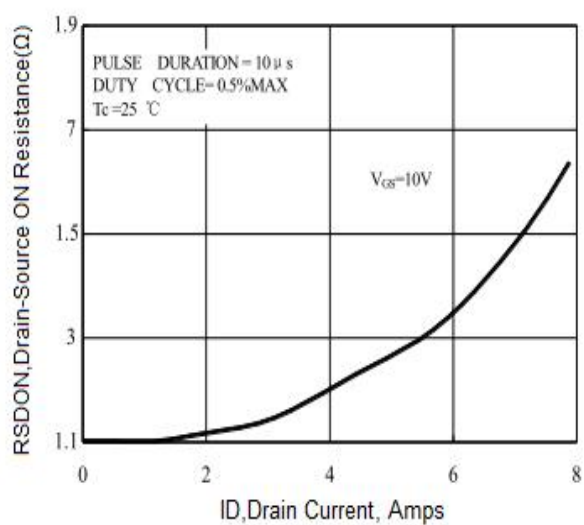
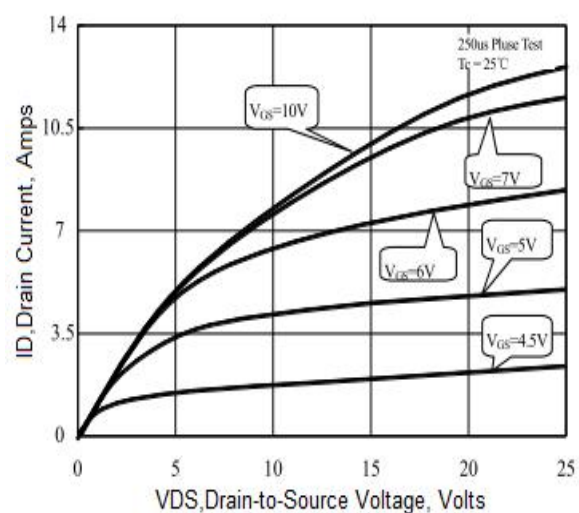
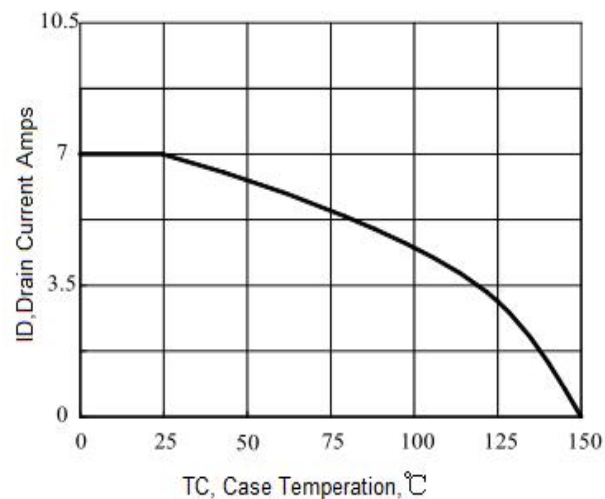
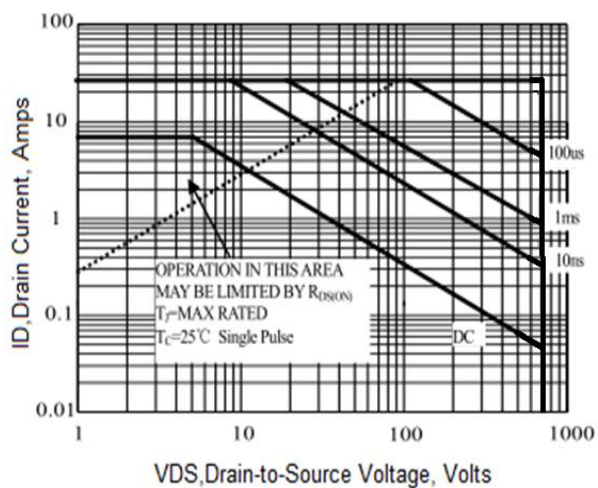
Characteristics	Test Condition	Symbol	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}, I_D = 250\text{ }\mu\text{A}$	BV_{DSS}	700	715	-	V
Drain-Source Leakage Current	$V_{DS} = 700\text{ V}, V_{GS} = 0\text{ V}$	I_{DSS}	-	-	1	μA
Gate Leakage Current	$V_{GS} = \pm 30\text{ V}, V_{DS} = 0\text{ V}$	I_{GSS}	-	-	± 100	nA
Gate-Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\text{ }\mu\text{A}$	$V_{GS(th)}$	2	-	4	V
Drain-Source On-State Resistance	$V_{GS} = 10\text{ V}, I_D = 3.5\text{ A}$	$R_{DS(on)}$	-	1.45	1.86	Ω
Forward Transconductance	$V_{DS} = 15\text{ V}, I_D = 3.5\text{ A}$	g_{fs}	-	6.5	-	S
Input Capacitance	$V_{GS} = 0\text{ V}, V_{DS} = 2\text{ V},$ $f = 200\text{ KHz}$	C_{iss}	-	1334	-	pF
Output Capacitance		C_{oss}	-	92	-	pF
Reverse Transfer Capacitance		C_{rss}	-	5	-	pF
Turn-on Delay Time(Note2)	$I_D = 7\text{ A}, V_{DD} = 325\text{ V},$ $R_G = 10\Omega$	$t_{d(ON)}$	-	18	-	ns
Rise Time(Note2)		t_r	-	19	-	ns
Turn-Off Delay Time(Note2)		$t_{d(OFF)}$	-	39	-	ns
Fall Time(Note2)		t_f	-	18	-	ns
Total Gate Charge(Note2)	$I_D = 7\text{ A}, V_{DD} = 520\text{ V},$ $V_{GS} = 10\text{ V}$	Q_G	-	22	-	nC
Gate to Source Charge(Note2)		Q_{GS}	-	5	-	nC
Gate to Drain Charge(Note2)		Q_{GD}	-	9	-	nC

Source-Drain Diode Characteristics at $T_a=25^{\circ}\text{C}$ unless otherwise specified

Characteristics	Test Condition	Symbol	Min.	Typ.	Max.	Unit
Maximun Body-Diode Continuous Current		I_S	-	-	7	A
Maximun Body-Diode Pulsed Current(Note2)		I_{SM}	-	-	28	A
Drain-Source Diode Forward Voltage	$I_{SD} = 7\text{ A}$	V_{SD}	-	-	1.4	V
Reverse Recovery Time(Note2)	$I_{SD} = 7\text{ A}, V_{GS} = 0\text{ V},$ $dI_F /$	t_{rr}	-	370	-	ns
Reverse Recovery Charge(Note2)	$dt = 100\text{ A}/\mu\text{s}$	Q_{rr}	-	1.9	-	μC

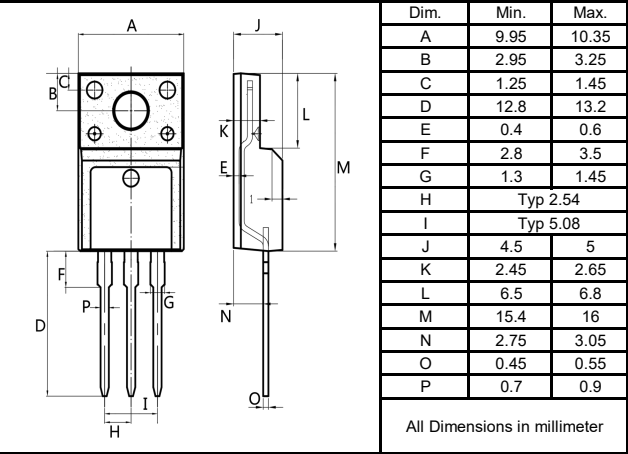
Note2:Pulse test: 300 μs pulse width, 2 % duty cycle

Typical Characteristics

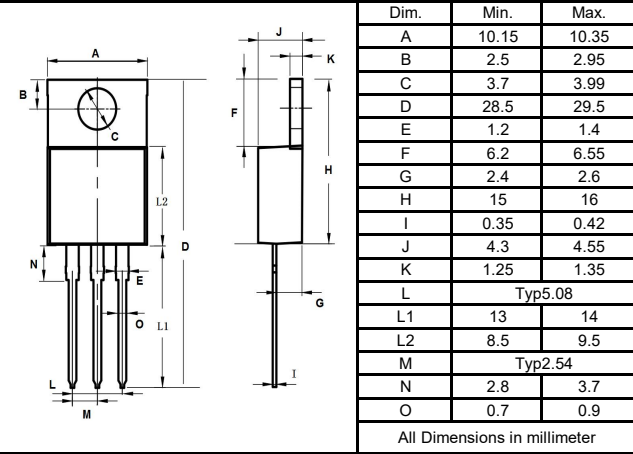


Package Outline Dimensions

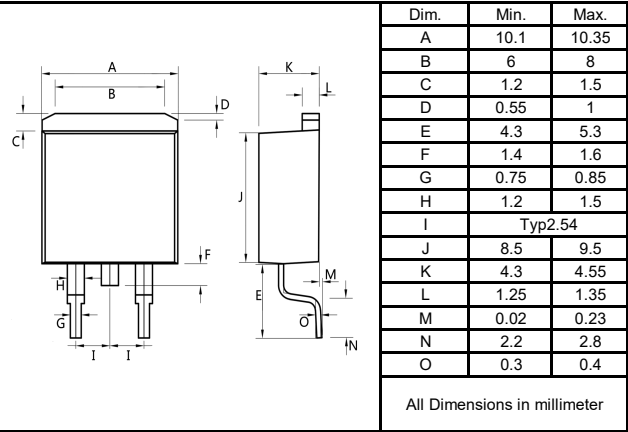
T0-220F



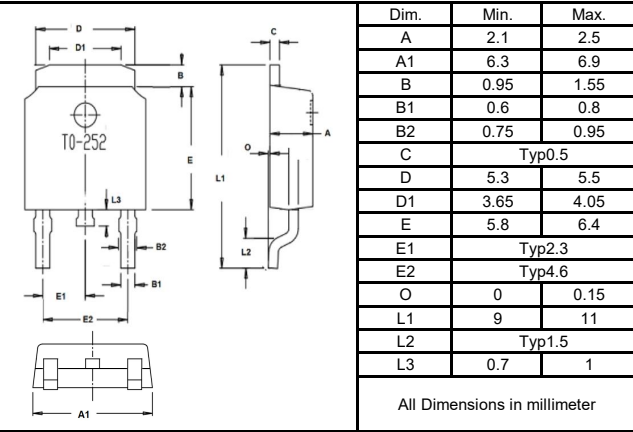
T0-220AB



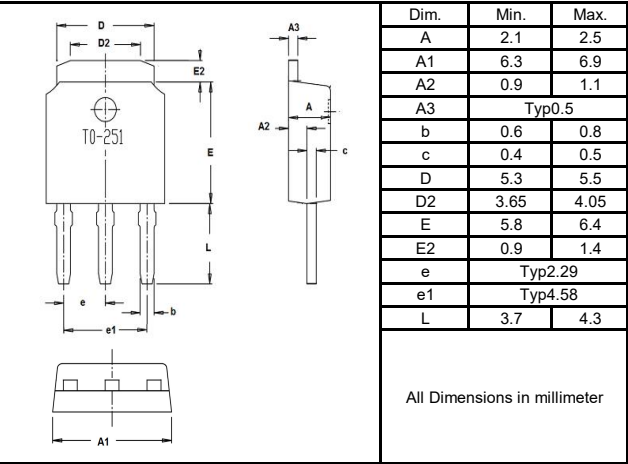
T0-263



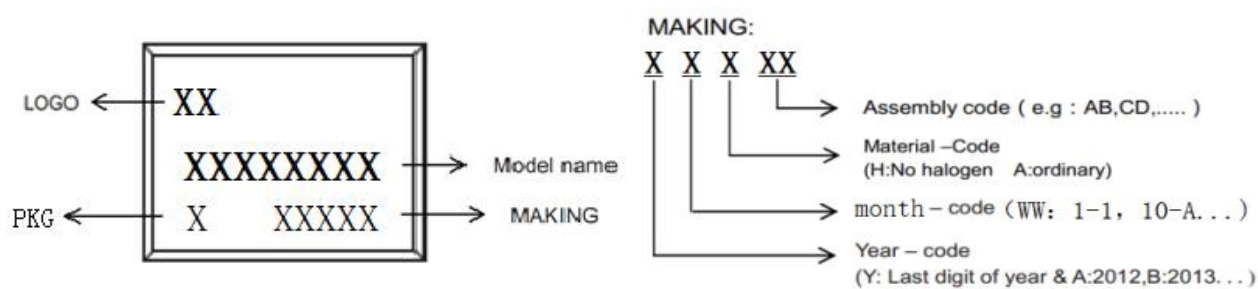
T0-252



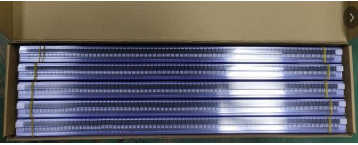
T0-251



Marking on the body



packing instruction

PKG	最小包装	内盒	外箱
TO-220F TO-220AB TO-263			
	50pcs/管	1000pcs/盒	5000pcs/箱
TO-252			
	2500pcs/盘	5000pcs/盒	25000pcs/箱
TO-263-R			
	800pcs/盘	1600pcs/盒	8000pcs/箱
TO-251			
	80pcs/管	4000pcs/盒	24000pcs/箱